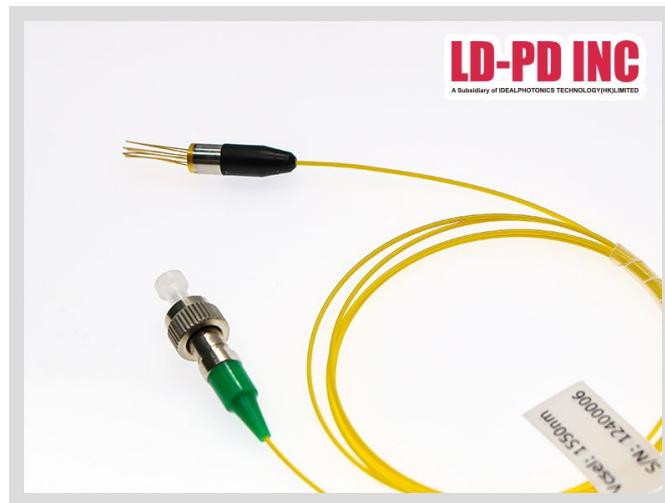


1550nm SM VCSEL Laser diode for 4.25Gbps High speed Communication



Description:

The PL-VCSEL-1550-0-A81- CPSA 1550nm VCSEL is a vertical emitting MOVPE grown GaAsP/AlGaAs Single Mode diode laser. Wavelength tuning can be achieved via laser current and temperature tuning. package with TEC and PD Built in. Our 1550 nm single mode VCSEL is designed for high-speed, high-performance communication applications.

Features:

- Low dependence of electrical and optical characteristics over temperature
- Data rates from OC-3 to OC-48
- Vertical Cavity Surface-Emitting Laser
- Internal TEC and Thermistor, ESD protection
- Narrow linewidth
- 2 nm tunability with TEC

Applications:

- Access network for long distance
- Local area network
- Gigabit Ethernet

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Electrical/Optical Characteristics:

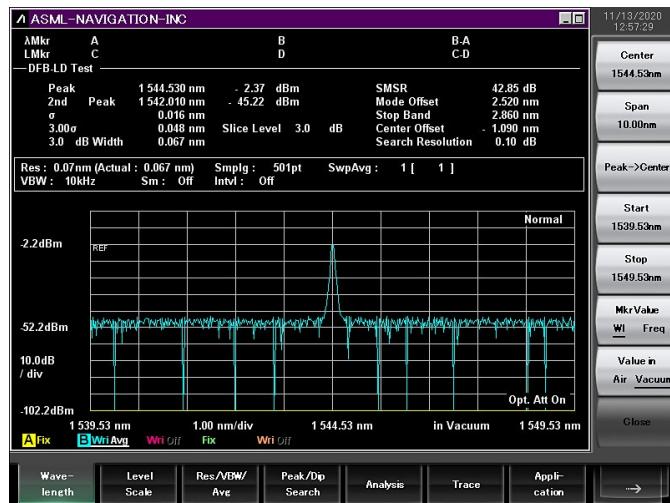
Condition: TO P = 20°C, IO P = 10.0 mA unless otherwise stated (TO P = chip backside temperature, controlled by the TEC)

Parameters	Symbol	Min	Typ	Max	Unit	Remark
Emission Wavelength	λ_R	1530-1570nm				1530-1570nm
Threshold current	I_{TH}		2		mA	
Output Power	P_{opt}	0.3	0.5	0.7	mW	
Threshold Voltage	U_{TH}		1.8		V	
Driving Current	I_{OP}			15	mA	$P_{opt} = 0.5\text{mW}$
Laser voltage	U_{OP}		3		V	$P_{opt} = 0.5 \text{ mW}$
Electro optic conversion rate	η_{WP}		12		%	$P_{opt} = 0.5 \text{ mW}$
Slope efficiency	η_S		0.3		W/A	
Rise and Fall time	T_r/T_f		90/120		Psec	
Differential series resistance	R_S		100	200	Ω	$P_{opt} = 0.5 \text{ mW}$
3dB bandwidth	v_{3dB}	0.10			GHz	$P_{opt} = 0.5 \text{ mW}$
						Due to ESD protection diode
Relative intensity noise	R_{IN}		-130	-120	dB/Hz	$P_{opt} = 0.3 \text{ mW @ 1 GHz}$
Wavelength tuning over current			0.6		nm/mA	
Wavelength tuning over temperature			0.06		nm/K	
Thermal resistance (VCSEL chip)	$R_{thermal}$	3		5	K/mW	
Side mode suppression		35			dB	$I = 2 \text{ mA}$
Beam divergence	θ	10		25	$^\circ$	$P_{opt} = 0.5\text{mW, full width } 1/e^2$
Spectral Width			100		MHz	$P_{opt} = 0.5 \text{ mW}$

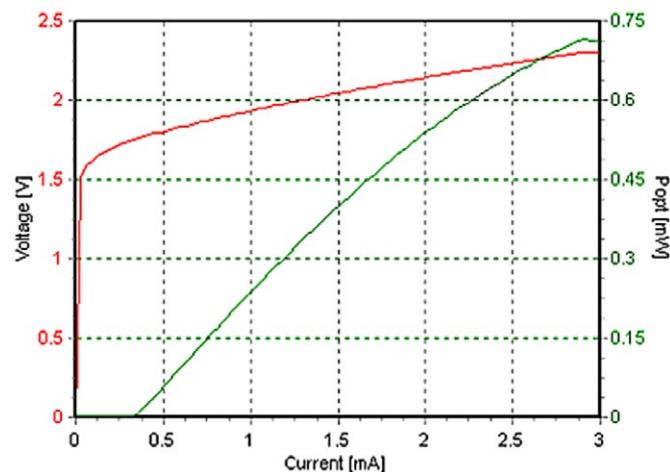
Tec Characteristics	Unit	Min	Typ	Max	Remark
Tec Current	mA	-150(Heating)		+300(Cooling)	Proper Heat Sink Required
NTC Thermistor Resistance	$K\Omega$	9.5	10.0	10.5	$T=25^\circ C @ 10 K\Omega$
NTC Thermistor Resistance	$K\Omega$	10/exp{3892-(1/289K-I/TOP)}			

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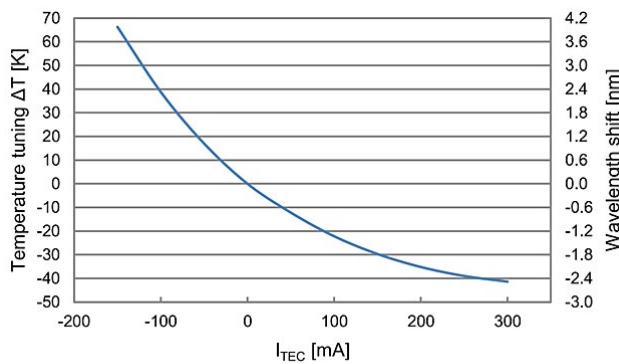
Spectrum:



L-I Curve(T@25°C):



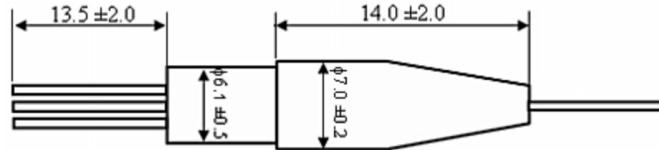
Temperature / wavelength tuning over TEC current*:



* TEC performance is dependent on heat load, ambient temperature and heatsink properties

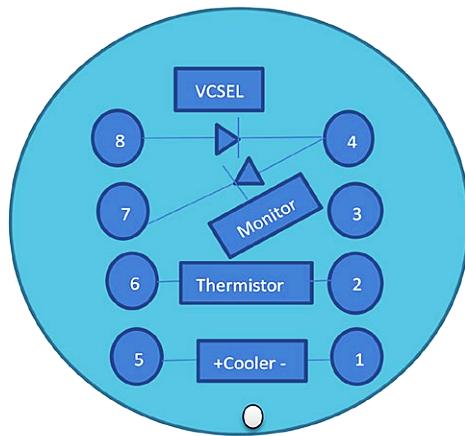
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Package Size:



TO package Bottom side View (Unit in mm)

Pin definition:



1	Thermoelectric Cooler (-)	5	Thermoelectric Cooler (+)
2	Thermistor	6	Thermistor
3	N/C	7	PD Monitor Cathode (+)
4	VCSEL Cathode (-)/PD Monitor Anode (-)	8	VCSEL Anode (+)

Absolute Maximum Ratings:

Item	Unit	Min	Typ	Max
Store Temperature	°C	-40	25	125
Chip Temperature	°C	+10	25	40
Operating Current	mA	0	3.0	15.0
Forward Voltage	V	0.8	1.2	1.8
TEC Current	mA	-150	-	+300
Soldering Temperature*	°C	100	130	260
Electrical Power Dissipation	mw	-	-	5

(*TEC temperature must be below 150°C)

Ordering Info:

PL-VCSEL-□□□□-☆-A8▽-XXXX

□□□□: Wavelength

0760:760nm

0850-850nm

1550: 1550nm

☆ : TEC

0: Without TEC

1: With TEC

▽: Wavelength Tolerance

1: ±0.5nm

2: ±1.5nm

XXXX: Fiber and Connector Type

FS=Free Space

BFSA=Butterfly Package with SMF-28E+ FC/APC

CPSA=Coaxial Package with SMF-28E+ FC/APC

BFSP=Butterfly Package with SMF-28E+ FC/PC

CPSP=Coaxial Package with SMF-28E+ FC/PC

BFPP=PM Fiber+ FC/PC

BFPA=PM Fiber+ FC/APC